## **SPICE Device Model Si7478DP**



Vishay Siliconix

# N-Channel 60 V (D-S) MOSFET

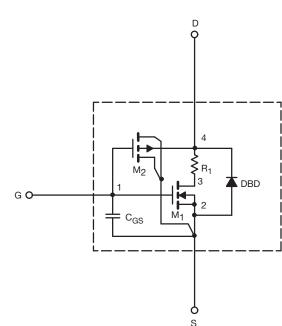
### DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics



### SUBCIRCUIT MODEL SCHEMATIC

#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.





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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1.8	-	V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \geq 5 \text{ V},  V_{GS} = 10 \text{ V}$	697	-	А
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	0.006	0.006	Ω
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 18.5 \text{ A}$	0.007	0.007	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	58	63	S
Diode Forward Voltage	V <sub>SD</sub>	$I_{S} = 4.5 \text{ A}, V_{GS} = 0 \text{ V}$	0.84	0.79	V
Dynamic <sup>b</sup>					
Total Gate Charge	Qg	$V_{DS}$ = 30 V, $V_{GS}$ = 10 V, $I_{D}$ = 20 A	105	105	nC
Gate-Source Charge	Q <sub>gs</sub>		22	22	
Gate-Drain Charge	Q <sub>gd</sub>		10	10	
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD} = 30 \text{ V}, \text{ R}_{\text{L}} = 30 \ \Omega$ $\text{I}_{\text{D}} = 1 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 6 \ \Omega$	32	25	ns
Rise Time	t <sub>r</sub>		31	20	
Turn-Off Delay Time	t <sub>d(off)</sub>		51	115	
Fall Time	t <sub>f</sub>		53	45	

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

60 10, 7, 6, 5, 4 V VGS 50 I<sub>D</sub> – Drain Current (A) 40

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60

50

40

30

30

с

125°C

3.0 3.5 4.0

50

60

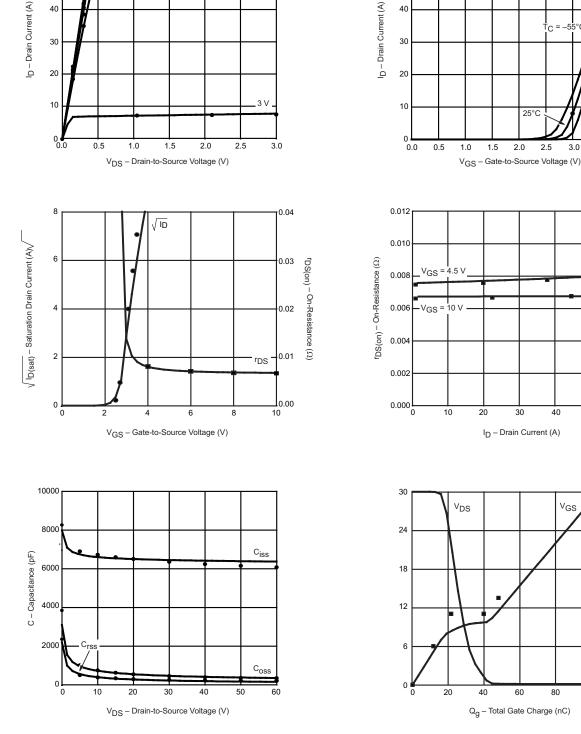
10

6

120<sup>0</sup>

100

## COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)



### Note

• Dots and squares represent measured data.

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